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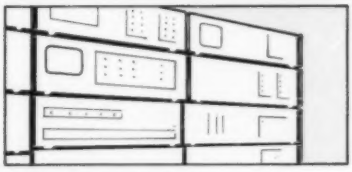

News and analysis

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- ☐ Manufacturers wrestle with MATE requirements (Aug, 47)
- ☐ Automation comes to YIG filter testing (Aug, 51)

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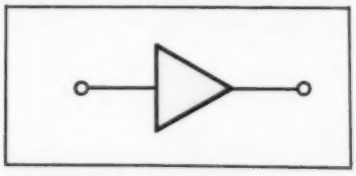
- ☐ Complete test station is transportable (Jan, 229)
- ☐ Software system analyzes devices (Sep, 192)
- ☐ Test EMI automatically with analyzer software (Nov, 206)

Amplifiers and oscillators



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- ☐ Use internal feedback to drop amplifier VSWR (Apr, 71)
- ☐ A 180-MHz synthesizer from a $10 CMOS chip (Apr, 75)
- ☐ Power devices drive tunable oscillators (May, 179)
- ☐ Wideband DMOS amplifier competes with bipolars (Jun, 113)
- ☐ Matching technique yields optimum LNA performance (Feb, 87)
- ☐ Use YTHGs for better frequency accuracy (Jul, 107)
- ☐ Preamps and YTOs cut ELINT noise (Sep, 121)
- ☐ Room light: The gremlin clouding amplifier tests (Oct, 75)
- ☐ CAD software optimizes DRO embedding network (Oct, 79)
- ☐ Signal source specs hold key to receiver tests (Nov, 129)

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- ☐ SAW subsystem analyzes LF spectrum (Mar, 177)
- ☐ Speedy VCO tunes 8 to 12 GHz (Aug, 121)
- ☐ Operational amp buffers 165 MHz (Jan, 149)
- ☐ High-speed opamp has wide bandwidth (Mar, 177)
- ☐ Cubic YIG components save time and space (Apr, 115)
- ☐ Atomic oscillator fits in your palm (Apr, 127)
- ☐ Kilowatt amplifier spans 30 to 150 MHz (Apr, 133)
- ☐ Oscillator offers reference retrofit (Apr, 145)
- ☐ Amp modules boast wide dynamic range (Apr, 146)
- ☐ Monolithic logamp challenges hybrids (May, 203)
- ☐ SAW oscillator serves optic links (May, 227)
- ☐ High-speed logamp surveys 2 to 6 GHz (Jul, 135)
- ☐ PLL stabilizes DRO sources (Jul, 139)
- ☐ Front-end lineup fits in flatpacks (Aug, 127)
- ☐ High-gain amplifier powers 6 to 18 GHz (Sep, 197)
- ☐ Microprocessor governs cesium frequency standard (Oct, 131)
- ☐ Track-and-hold amp switches in 10 ns (Oct, 214)
- ☐ VCO tunes 1 to 2 GHz with +13 dBm (Oct, 215)
- ☐ Thin-film GaAs FETs amplify 2 to 18 GHz (Nov, 150)

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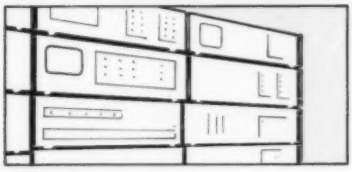

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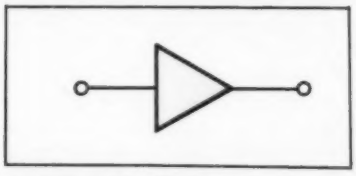

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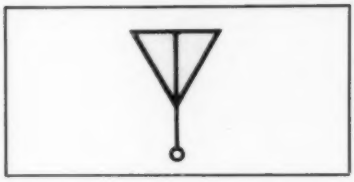

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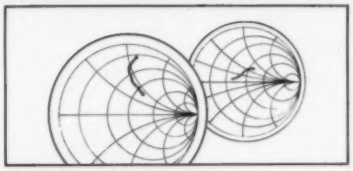

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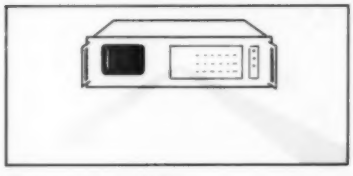

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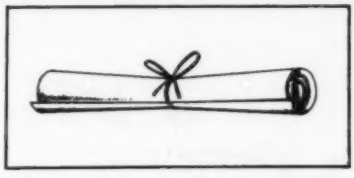

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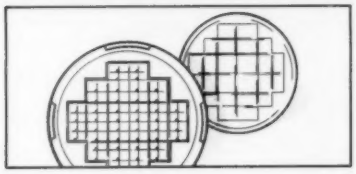
ICs and MMICs



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- ☐ You bring the specs, they make the wafer (Jun, 83)
- ☐ GaAs MMICs poised for production (Mar, 65)
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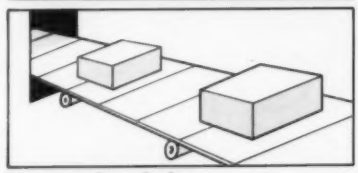

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- ☐ Digital demands drive MW design (Jun, 67)
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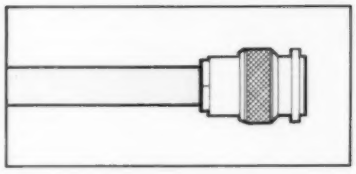

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- ☐ Of vanishing filters and wishful thinking (May, 219)
- ☐ Keeping account of connector standards (Nov, 70)
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- ☐ More challenges ahead for connector design (Nov, 87)
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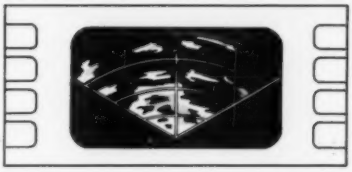

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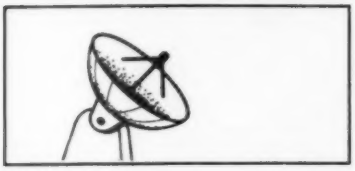

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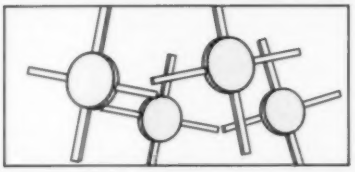

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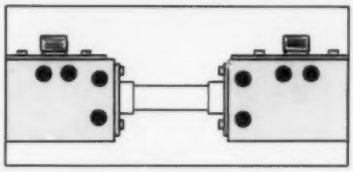

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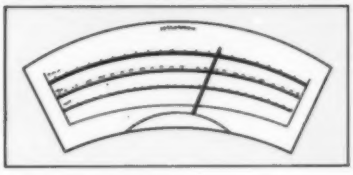

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